

DECLARATION OF JOINT INVENTORS FOR PATENT APPLICATION

As the below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and joint inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled "Methods of Treating Dielectric Materials With Oxygen, and Methods of Forming Capacitor Constructions", filed with the United States Patent and Trademark Office on August 30, 2001 and assigned Serial No. 09/945,308.

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims.

I acknowledge the duty to disclose information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations § 1.56.

PRIOR FOREIGN APPLICATIONS:

I hereby state that no applications for foreign patents or inventor's certificates have been filed prior to the date of execution of this declaration.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such

EL979955077
EV077334813

willful false statement may jeopardize the validity of the application or any patent issued therefrom.

* * * * *

Full name of inventor: Gurtej S. Sandhu

Inventor's Signature:



Date:

10/24/01

Residence: Boise, Idaho

Citizenship: UK

Post Office Address: 2964 E. Parkriver Drive,
Boise, ID 83706

* * * * *

Full name of inventor: Trung Tri Doan

Inventor's Signature:



Date:

11/07/01

Residence: Boise, Idaho

Citizenship: USA

Post Office Address: 1574 Shenandoah Drive
Boise, ID 83712